

**Amendments to the Claims:**

This listing of claims will replace all prior versions, and listings, of claims in the application:

1. (Currently Amended) A liquid crystal display device comprising:  
a thin film transistor ~~including a gate electrode formed by a droplet discharge method;~~  
~~a eolumnar conductive film projection formed by a droplet discharge method~~ over a drain electrode of the thin film transistor; and  
a pixel electrode connected to the ~~eolumnar conductive film projection,~~  
wherein the projection has a stacked structure.
2. (Currently Amended) The liquid crystal display device according to claim 1,  
wherein [[the]] a gate electrode of the thin film transistor is formed over an area which is pretreated.
3. (Original) The liquid crystal display device according to claim 2,  
wherein the area which is pretreated is formed using photocatalyst.
4. (Currently Amended) The liquid crystal display device according to claim 1,  
wherein at least one of the gate electrode, the drain electrode, and the ~~eolumnar conductive film projection~~ contains one selected from the group consisting of gold, silver, copper, platinum, palladium, tungsten, nickel, tantalum, bismuth, lead, indium, tin, zinc, titanium, and aluminum.
5. (Original) The liquid crystal display device according to claim 1,  
wherein the thin film transistor includes an amorphous semiconductor or a semiamorphous semiconductor.

6. (Original) A television receiver, wherein the liquid crystal display device according to claim 1 is included in a display screen of the television receiver.

7.-12. (Canceled)

13. (New) A liquid crystal display device comprising:  
a pixel portion including a thin film transistor, a first projection over a drain electrode of the thin film transistor and a pixel electrode connected to the first projection; and  
a terminal portion including a wiring, a second projection over the wiring and a terminal electrode connected to the second projection,  
wherein each of the first projection and the second projection has a stacked structure.

14. (New) The liquid crystal display device according to claim 13,  
wherein a gate electrode of the thin film transistor is formed over an area which is pretreated.

15. (New) The liquid crystal display device according to claim 14,  
wherein the area which is pretreated is formed using photocatalyst.

16. (New) The liquid crystal display device according to claim 13,  
wherein at least one of the gate electrode, the drain electrode, the first projection, and the second projection contains one selected from the group consisting of gold, silver, copper, platinum, palladium, tungsten, nickel, tantalum, bismuth, lead, indium, tin, zinc, titanium, and aluminum.

17. (New) The liquid crystal display device according to claim 13,  
wherein the thin film transistor includes an amorphous semiconductor or a semiamorphous semiconductor.

18. (New) A television receiver, wherein the liquid crystal display device according to claim 13 is included in a display screen of the television receiver.